



THE DATASHEET OF MOC208M



MOC205-M

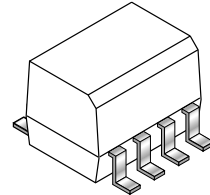
MOC206-M

MOC207-M

MOC208-M

DESCRIPTION

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high density applications, and eliminate the need for through - the - board mounting.

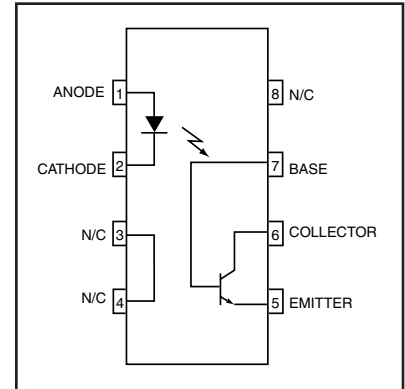


FEATURES

- U.L. Recognized (File #E90700, Volume 2)
- VDE Recognized (File #136616) (add option "V" for VDE approval, i.e, MOC205V-M)
- Closely Matched Current Transfer Ratios
- Convenient Plastic SOIC-8 Surface Mountable Package Style
- Minimum BV_{CEO} of 70 Volts Guaranteed
- Standard SOIC-8 Footprint, with 0.050" Lead Spacing
- Compatible with Dual Wave, Vapor Phase and IR Reflow Soldering
- High Input-Output Isolation of 2500 $V_{AC(rms)}$ Guaranteed

APPLICATIONS

- Feedback Control Circuits
- Interfacing and coupling systems of different potentials and impedances
- General Purpose Switching Circuits
- Monitor and Detection Circuits



MOC205-M

MOC206-M

MOC207-M

MOC208-M

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless otherwise specified)			
Rating	Symbol	Value	Unit
EMITTER			
Forward Current - Continuous	I_F	60	mA
Forward Current - Peak (PW = 100 μs , 120 pps)	I_F (pk)	1.0	A
Reverse Voltage	V_R	6.0	V
LED Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	90 0.8	mW mW/ $^\circ\text{C}$
DETECTOR			
Collector-Emitter Voltage	V_{CEO}	70	V
Emitter-Collector Voltage	V_{ECO}	7.0	V
Collector-Base Voltage	V_{CBO}	70	V
Collector Current-Continuous	I_C	150	mA
Detector Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	150 1.76	mW mW/ $^\circ\text{C}$
TOTAL DEVICE			
Input-Output Isolation Voltage (1,2,3) (f = 60 Hz, t = 1 min.)	V_{ISO}	2500	Vac(rms)
Total Device Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	250 2.94	mW mW/ $^\circ\text{C}$
Ambient Operating Temperature Range	T_A	-40 to +100	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-40 to +150	$^\circ\text{C}$

MOC205-M

MOC206-M

MOC207-M

MOC208-M

ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise specified)						
Parameter	Test Conditions	Symbol	Min	Typ**	Max	Unit
EMITTER						
Input Forward Voltage	(I _F = 10 mA)	V _F	—	1.15	1.5	V
Reverse Leakage Current	(V _R = 6.0 V)	I _R	—	0.001	100	μA
Input Capacitance		C _{IN}	—	18	—	pF
DETECTOR						
Collector-Emitter Dark Current	(V _{CE} = 10 V, T _A = 25°C)	I _{CEO1}	—	1.0	50	nA
	(V _{CE} = 10 V, T _A = 100°C)	I _{CEO2}	—	1.0	—	μA
Collector-Emitter Breakdown Voltage	(I _C = 100 μA)	BV _{CEO}	70	100	—	V
Emitter-Collector Breakdown Voltage	(I _E = 100 μA)	BV _{ECO}	7.0	10	—	V
Collector-Emitter Capacitance	(f = 1.0 MHz, V _{CE} = 0)	C _{CE}	—	7.0	—	pF
COUPLED						
Collector-Output Current ⁽⁴⁾	MOC205-M MOC206-M MOC207-M MOC208-M (I _F = 10 mA, V _{CE} = 10 V)	CTR	40 63 100 40	— — — —	80 125 200 125	%
Isolation Surge Voltage ^(1,2,3)	(f = 60 Hz AC Peak, t = 1 min.)	V _{ISO}	2500	—	—	Vac(rms)
Isolation Resistance ⁽²⁾	(V = 500 V)	R _{ISO}	10 ¹¹	—	—	Ω
Collector-Emitter Saturation Voltage	(I _C = 2 mA, I _F = 10 mA)	V _{CE(sat)}	—	—	0.4	V
Isolation Capacitance ⁽²⁾	(V = 0 V, f = 1 MHz)	C _{ISO}	—	0.2	—	pF
Turn-On Time	(I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω) (Fig. 6)	t _{on}	—	7.5	—	μs
Turn-Off Time	(I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω) (Fig. 6)	t _{off}	—	5.7	—	μs
Rise Time	(I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω) (Fig. 6)	t _r	—	3.2	—	μs
Fall Time	(I _C = 2.0 mA, V _{CC} = 10 V, R _L = 100 Ω) (Fig. 6)	t _f	—	4.7	—	μs

** Typical values at T_A = 25°C

1. Isolation Surge Voltage, V_{ISO}, is an internal device dielectric breakdown rating.
2. For this test, Pins 1 and 2 are common and Pins 5, 6 and 7 are common.
3. V_{ISO} rating of 2500 V_{AC(rms)} for t = 1 min. is equivalent to a rating of 3,000 V_{AC(rms)} for t = 1 sec.
4. Current Transfer Ratio (CTR) = I_C/I_F x 100%.

MOC205-M

MOC206-M

MOC207-M

MOC208-M

Fig. 1 LED Forward Voltage vs. Forward Current

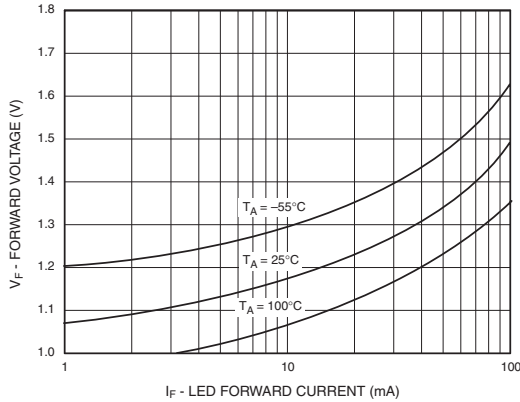


Fig. 2 Output Current vs. Input Current

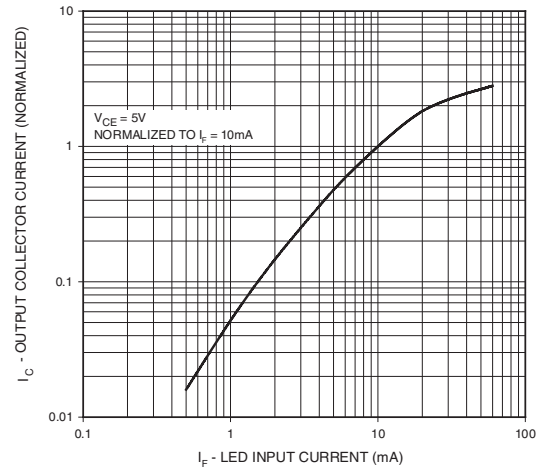


Fig. 3 Output Current vs. Ambient Temperature

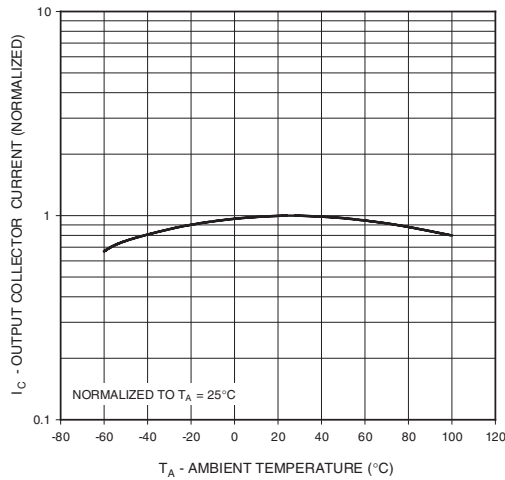


Fig. 4 Output Current vs. Collector - Emitter Voltage

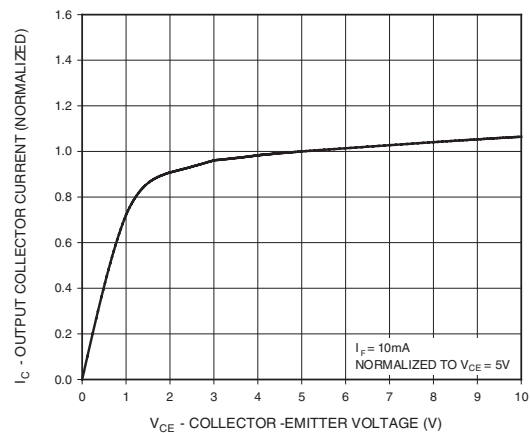


Fig. 5 Dark Current vs. Ambient Temperature

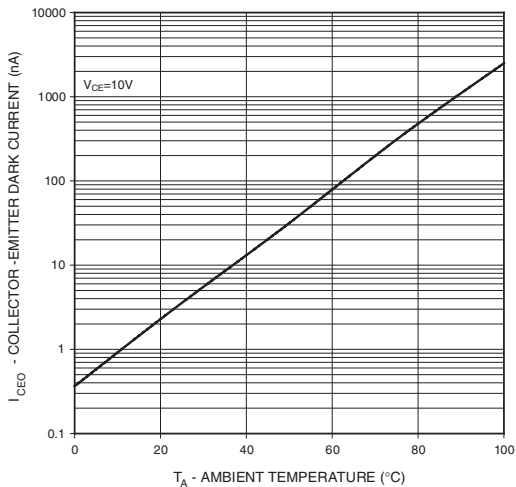
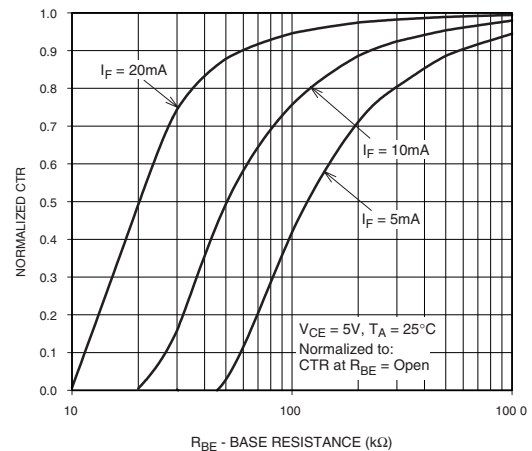


Fig. 6 CTR vs. RBE (Unsaturated)



MOC205-M

MOC206-M

MOC207-M

MOC208-M

Fig. 7 CTR vs. R_{BE} (Saturated)

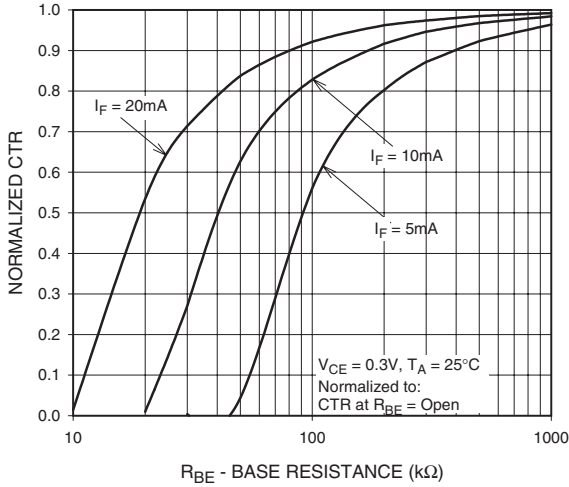


Fig. 8 Normalized t_{on} vs. R_{BE}

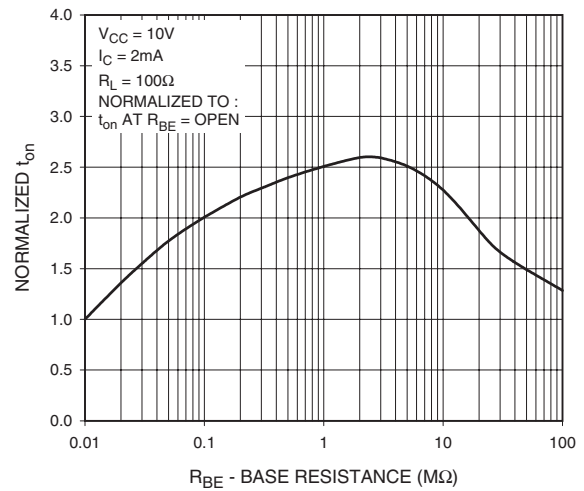
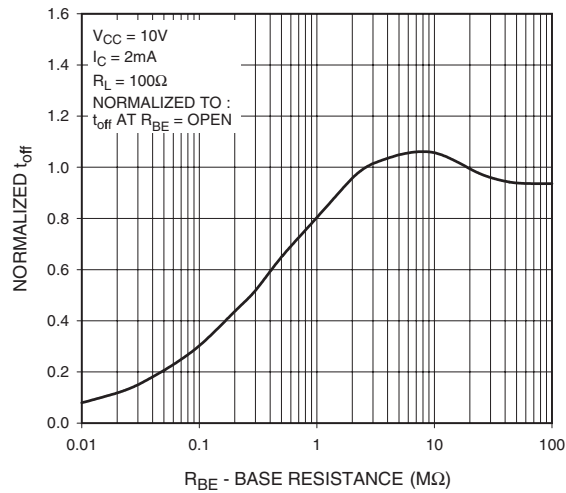


Fig. 9 Normalized t_{off} vs. R_{BE}



MOC205-M

MOC206-M

MOC207-M

MOC208-M

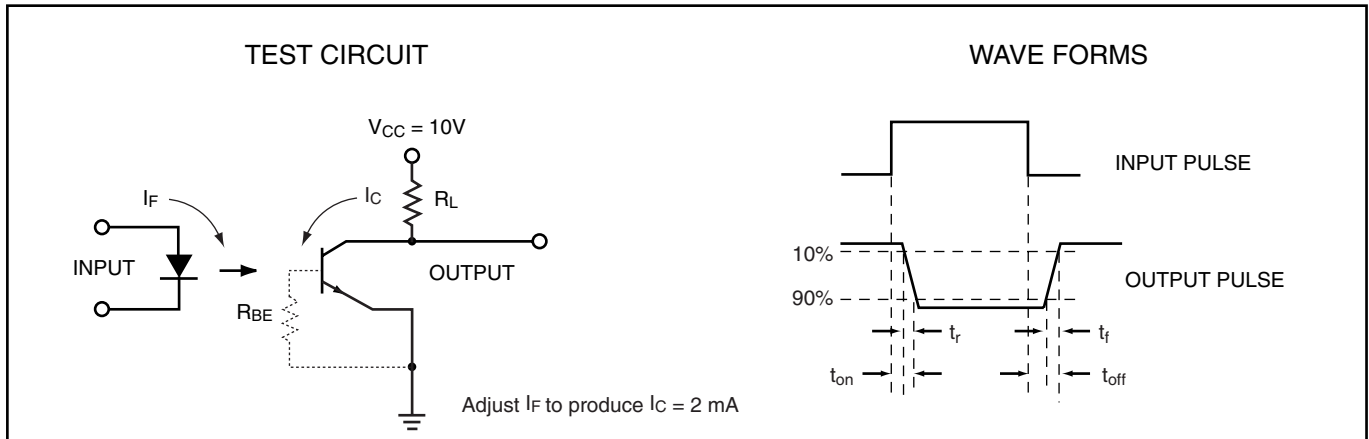


Figure 6. Switching Time Test Circuit and Waveforms

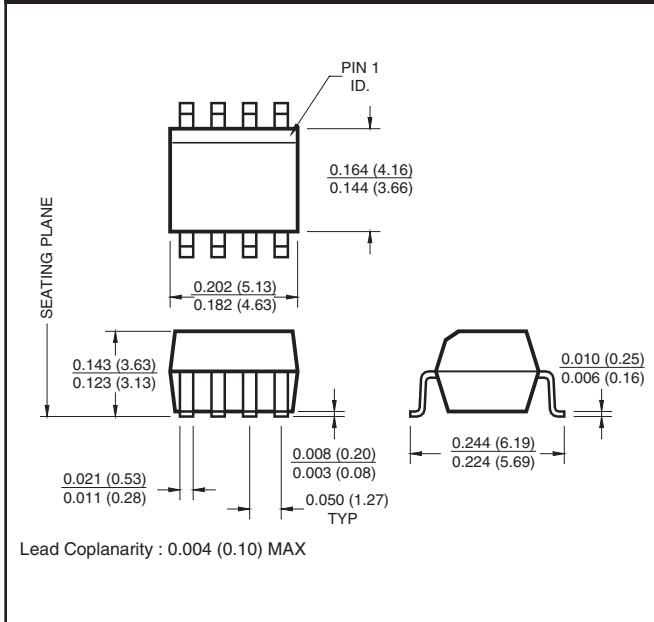
MOC205-M

MOC206-M

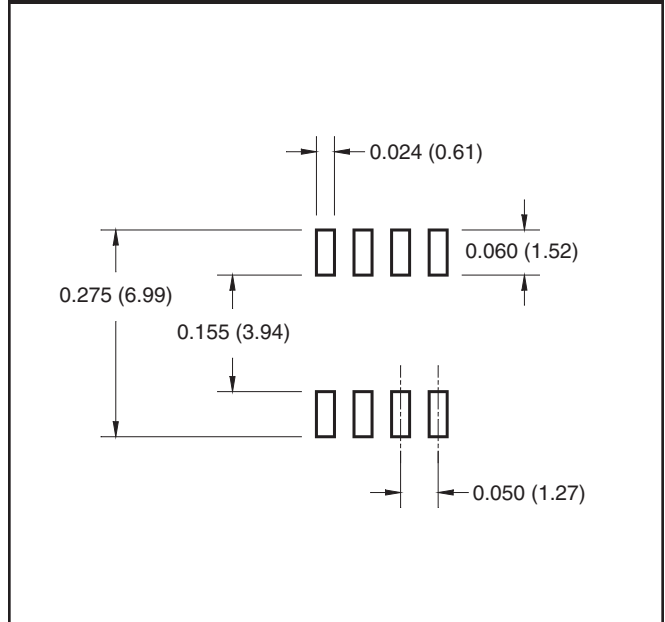
MOC207-M

MOC208-M

Package Dimensions (Surface Mount)



8-Pin Small Outline



MOC205-M

MOC206-M

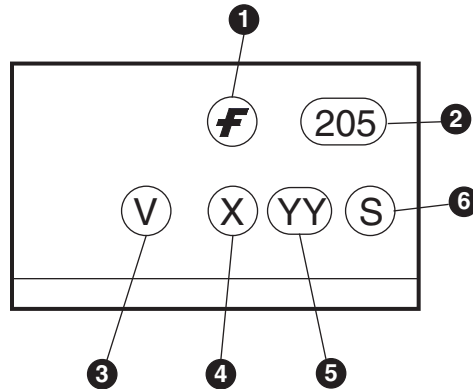
MOC207-M

MOC208-M

ORDERING INFORMATION

Option	Order Entry Identifier	Description
V	V	VDE 0884
R1	R1	Tape and reel (500 units per reel)
R1V	R1V	VDE 0884, Tape and reel (500 units per reel)
R2	R2	Tape and reel (2500 units per reel)
R2V	R2V	VDE 0884, Tape and reel (2500 units per reel)

MARKING INFORMATION



Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

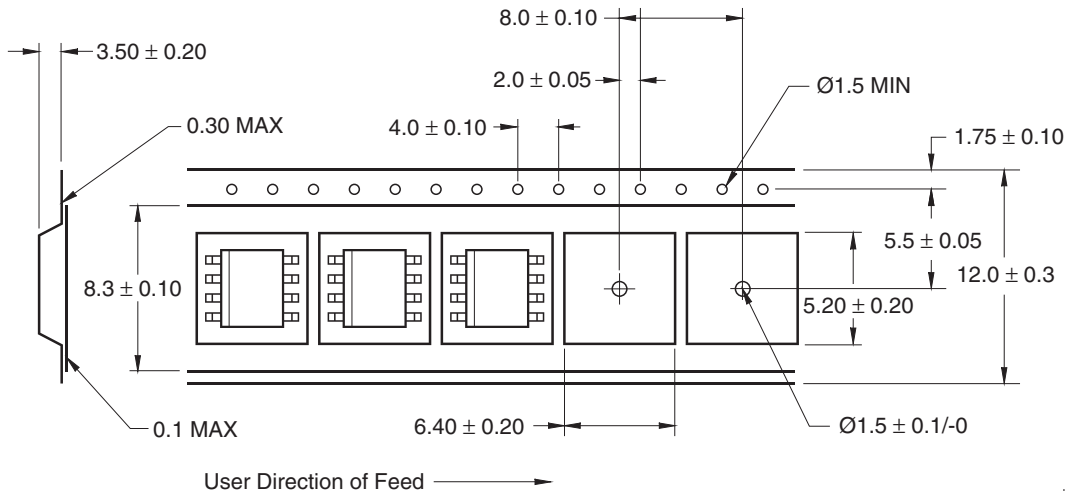
MOC205-M

MOC206-M

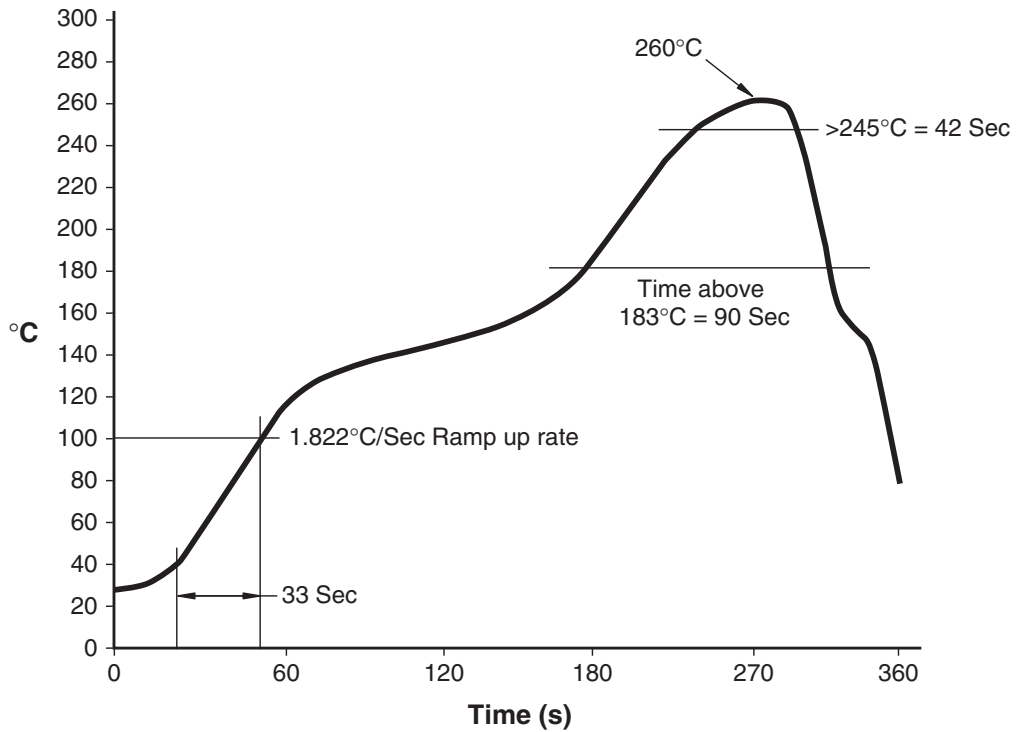
MOC207-M

MOC208-M

Carrier Tape Specifications



Reflow Profile



MOC205-M

MOC206-M

MOC207-M

MOC208-M

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- ⊖ [View MOC208M on WIN SOURCE](#)
- ⊖ [Fairchild/ON Semiconductor Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management